

T-RAM Names Sam R. Nakib President and CEO

MILPITAS, Calif. -- Sam R. Nakib has joined T-RAM Semiconductor as President and Chief Executive Officer, it was announced today by the company. He will also serve as a member of the Board of Directors.

Mr. Nakib is an industry veteran with over 30 years' experience in the semiconductor industry in areas of marketing and sales, business development and general management. Most recently, he was President and CEO of BerkEnna Wireless, when it introduced the first fully integrated, CMOS, cellular RF transceiver for GSM/GPRS. While at BerkEnna, Mr. Nakib also oversaw development of the next-generation 3.5G transceiver, and directed the company's acquisition by Qualcomm in December 2005.

Before BerkEnna, Mr. Nakib served as Senior Vice President of Business Development and Tactical Marketing at Cypress Semiconductor, and was Senior Vice President of Worldwide Sales at IC Works when it was acquired by Cypress. Prior to that, he was with Texas Instruments for 18 years in senior international sales and management positions. In addition, Mr. Nakib serves on the Board of Directors of Mobius Microsystems. He holds a Bachelor of Science Degree in Biochemistry from California State.

"We are delighted to have Sam bring his experience in developing successful business enterprises and strategic partnerships to lead T-RAM as it progresses towards commercialization of its innovative SRAM memory process technology," said Dado Banatao, Chairman of the Board at T-RAM, and a Managing Partner of Tallwood Venture Capital.

"I am very excited to join T-RAM at this time," said Mr. Nakib. "For years, system designers have dreamed of a memory device combining the performance of SRAM and the features of DRAMs. We've developed that technology and are successfully bringing it to market to address those needs."

About T-RAM Semiconductor, Inc. (www.t-ram.com)

T-RAM is a fabless semiconductor company developing a novel SRAM memory process technology, TCCT[™] (Thin-Capacitively-Coupled-Thyristor), which is expected to have the high performance of SRAM but with a memory cell size approaching that of DRAM. The company was founded in 2000, and has received venture funding from CenterPoint Ventures, InterWest Partners Mayfield, NEA, Tallwood Venture Capital and US Venture Partners.

T-RAM Semiconductor, Inc. is located at 620 N. McCarthy Boulevard, Milpitas, CA 95035. For more information: info@t-ram.com; 408-597-3000

COPYRIGHT 2006 Business Wire

COPYRIGHT 2008 Gale, Cengage Learning